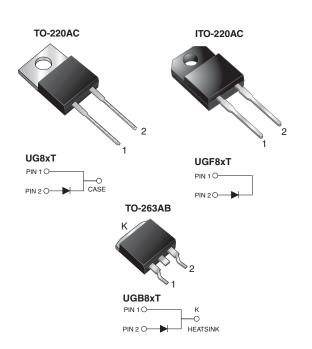


Vishay General Semiconductor

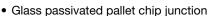
Ultrafast Rectifier



PRIMARY CHARACTERISTICS					
I _{F(AV)}	8.0 A				
V_{RRM}	50 V to 200 V				
I _{FSM}	150 A				
t _{rr}	20 ns				
V _F at I _F	0.95 V				
T _J max.	150 °C				
Package	TO-220AC, ITO-220AC, TO-263AB				
Diode variations	Single die				

FEATURES







· Low switching losses, high efficiency

High forward surge capability

ROHS COMPLIANT

 Meets MSL level 1, per J-STD-020, LF maximum peak of 245 °C (for TO-263AB package)

 Solder dip 275 °C max., 10 s per JESD 22-B106 (for TO-220AC and ITO-220AC package)

• AEC-Q101 qualified

 Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>

TYPICAL APPLICATIONS

For use in high frequency rectifier of switching mode power supplies, inverters, freewheeling diodes, DC/DC converters, and other power switching application.

MECHANICAL DATA

Case: TO-220AC, ITO-220AC, TO-263AB

Molding compound meets UL 94V-0 flammability rating Base P/N-E3 - RoHS-compliant, commercial grade Base P/NHE3 - RoHS-compliant, AEC-Q101 gualified

Terminals: Matte tin plated leads, solderable per J-STD-002 and JESD22-B102

E3 suffix meets JESD 201 class 1A whisker test, HE3 suffix meets JESD 201 class 2 whisker test

Polarity: As marked

Mounting Torque: 10 in-lbs max.

MAXIMUM RATINGS (T _C = 25 °C unless otherwise noted)							
PARAMETER	SYMBOL	UG8AT	UG8BT	UG8CT	UG8DT	UNIT	
Max. repetitive peak reverse voltage	V_{RRM}	50	100	150	200	V	
Max. RMS voltage	V _{RMS}	35	70	105	140	V	
Max. DC blocking voltage	V_{DC}	50	100	150	200	V	
Max. average forward rectified current at T _C = 100 °C	I _{F(AV)}	8.0				Α	
Peak forward surge current 8.3 ms single half sine-wave superimposed on rated load	I _{FSM}	150				А	
Operating junction and storage temperature range	T _J , T _{STG}	-55 to +150				°C	
Isolation voltage (ITO-220AC only) from terminals to heatsink t = 1 min	V _{AC}	1500				V	

UG8xT, UGF8xT, UGB8xT

Vishay General Semiconductor

ELECTRICAL CHARACTERISTICS (T _C = 25 °C unless otherwise noted)									
PARAMETER	TEST CONDIT	TIONS	SYMBOL	L UG8AT UG8BT UG8CT UG8DT				UNIT	
Max. instantaneous forward voltage	8.0 A			1.0					
	20.0 A	T _J = 150 °C	V _F ⁽¹⁾	1.2				V	
	5.0 A			0.95					
Max. DC reverse current at rated		T _J = 25 °C			1	0			
DC blocking voltage		T _J = 100 °C		300				μA	
Max. reverse recovery time	$I_F = 0.5 \text{ A}, I_R = 1.0 \text{ A}, I_r$	_r = 0.25 A	t _{rr}	20				ns	
	$I_F = 8.0 \text{ A}, V_R = 30 \text{ V},$	T _J = 25 °C		30					
Max. reverse recovery time	dl/dt = 50 A/µs, I _{rr} = 10 % I _{RM}	T _J = 100 °C	t _{rr}	50				ns	
Max. recovered stored charged	$I_F = 8.0 \text{ A}, V_R = 30 \text{ V},$	T _J = 25 °C	Q _{rr}	20				nC	
	dl/dt = 50 A/µs	T _J = 100 °C	Q _{rr}		4	45			
Typical junction capacitance	4.0 V, 1 MHz		CJ	45			рF		

Note

 $^{^{(1)}\,}$ Pulse test: 300 μs pulse width, 1 % duty cycle

THERMAL CHARACTERISTICS (T _C = 25 °C unless otherwise noted)						
PARAMETER	SYMBOL	UG8xT	UGF8xT	UGB8xT	UNIT	
Typical thermal resistance from junction to case	R ₀ JC (1)	4.0	5.0	4.0	°C/W	

ORDERING INFORMATION (Example)								
PACKAGE	PREFERRED P/N	UNIT WEIGHT (g)	PACKAGE CODE	BASE QUANTITY	DELIVERY MODE			
TO-220AC	UG8DT-E3/45	1.80	45	50/tube	Tube			
ITO-220AC	UGF8DT-E3/45	1.95	45	50/tube	Tube			
TO-263AB	UGB8DT-E3/45	1.33	45	50/tube	Tube			
TO-263AB	UGB8DT-E3/81	1.33	81	800/reel	Tape and reel			
TO-220AC	UG8DTHE3/45 (1)	1.80	45	50/tube	Tube			
ITO-220AC	UGF8DTHE3/45 (1)	1.95	45	50/tube	Tube			
TO-263AB	UGB8DTHE3/45 (1)	1.33	45	50/tube	Tube			
TO-263AB	UGB8DTHE3/81 (1)	1.33	81	800/reel	Tape and reel			

Note

⁽¹⁾ AEC-Q101 qualified

Vishay General Semiconductor

RATINGS AND CHARACTERISTICS CURVES (T_A = 25 °C unless otherwise noted)

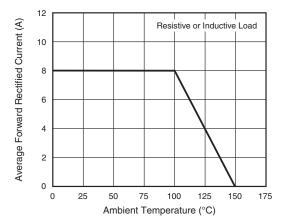


Fig. 1 - Max. Forward Current Derating Curve

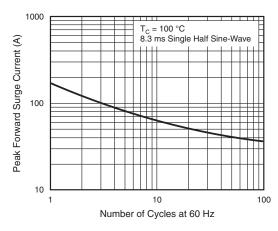


Fig. 2 - Max. Non-Repetitive Peak Forward Surge Current

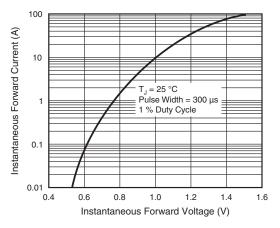


Fig. 3 - Typical Instantaneous Forward Characteristics

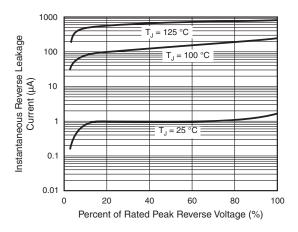


Fig. 4 - Typical Reverse Characteristics

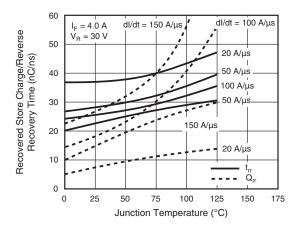


Fig. 5 - Reverse Switching Characteristics

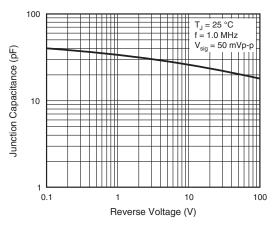
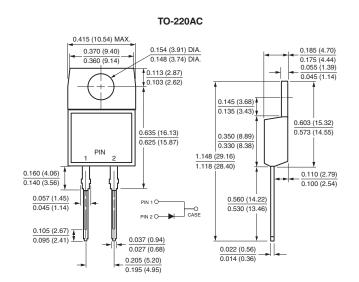


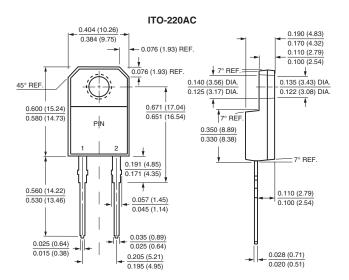
Fig. 6 - Typical Junction Capacitance



Vishay General Semiconductor

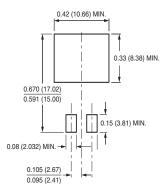
PACKAGE OUTLINE DIMENSIONS in inches (millimeters)





TO-263AB 0.411 (10.45) 0.190 (4.83) 0.380 (9.65) 0.160 (4.06) 0.055 (1.40) 0.245 (6.22) 0.045 (1.14) MIN. 0.055 (1.40) 0.360 (9.14) 0.047 (1.19) 0.320 (8.13) 0.624 (15.85) Κ 2 0.591 (15.00) -0 to 0.01 (0 to 0.254) 0.110 (2.79) 0.090 (2.29) 0.037 (0.940) 0.021 (0.53) 0.027 (0.686) 0.014 (0.36) 0.105 (2.67) 0.140 (3.56) 0.095 (2.41) 0.205 (5.20) 0.110 (2.79) 0.195 (4.95)

Mounting Pad Layout





Vishay

Disclaimer

ALL PRODUCT, PRODUCT SPECIFICATIONS AND DATA ARE SUBJECT TO CHANGE WITHOUT NOTICE TO IMPROVE RELIABILITY, FUNCTION OR DESIGN OR OTHERWISE.

Vishay Intertechnology, Inc., its affiliates, agents, and employees, and all persons acting on its or their behalf (collectively, "Vishay"), disclaim any and all liability for any errors, inaccuracies or incompleteness contained in any datasheet or in any other disclosure relating to any product.

Vishay makes no warranty, representation or guarantee regarding the suitability of the products for any particular purpose or the continuing production of any product. To the maximum extent permitted by applicable law, Vishay disclaims (i) any and all liability arising out of the application or use of any product, (ii) any and all liability, including without limitation special, consequential or incidental damages, and (iii) any and all implied warranties, including warranties of fitness for particular purpose, non-infringement and merchantability.

Statements regarding the suitability of products for certain types of applications are based on Vishay's knowledge of typical requirements that are often placed on Vishay products in generic applications. Such statements are not binding statements about the suitability of products for a particular application. It is the customer's responsibility to validate that a particular product with the properties described in the product specification is suitable for use in a particular application. Parameters provided in datasheets and / or specifications may vary in different applications and performance may vary over time. All operating parameters, including typical parameters, must be validated for each customer application by the customer's technical experts. Product specifications do not expand or otherwise modify Vishay's terms and conditions of purchase, including but not limited to the warranty expressed therein.

Hyperlinks included in this datasheet may direct users to third-party websites. These links are provided as a convenience and for informational purposes only. Inclusion of these hyperlinks does not constitute an endorsement or an approval by Vishay of any of the products, services or opinions of the corporation, organization or individual associated with the third-party website. Vishay disclaims any and all liability and bears no responsibility for the accuracy, legality or content of the third-party website or for that of subsequent links.

Except as expressly indicated in writing, Vishay products are not designed for use in medical, life-saving, or life-sustaining applications or for any other application in which the failure of the Vishay product could result in personal injury or death. Customers using or selling Vishay products not expressly indicated for use in such applications do so at their own risk. Please contact authorized Vishay personnel to obtain written terms and conditions regarding products designed for such applications.

No license, express or implied, by estoppel or otherwise, to any intellectual property rights is granted by this document or by any conduct of Vishay. Product names and markings noted herein may be trademarks of their respective owners.

单击下面可查看定价,库存,交付和生命周期等信息

>>Vishay(威世)